Diode Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Glass

### Overall Length:

Between 0.293 inches and 0.357 inches

# Terminal Length:

Between 1.000 inches and 1.625 inches

### **Overall Diameter:**

Between 0.215 inches and 0.235 inches

### **Function For Which Designed:**

Transient suppressor

### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-13

#### **Mounting Method:**

Terminal

#### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

53.6 breakdown voltage, dc

# Current Rating Per Characteristic:

1.00 milliamperes source cutoff current horsepower metric

# Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector major

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Terminal Type And Quantity:

2 uninsulated wire lead

#### **Specification Data:**

81349-mil-s-19500/507 government specification

#### Shelf Life:

N/a

### Unit Of Measure:

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#### Demilitarization:

No

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